

Phase Control Thyristors (Hockey PUK Version), 720 A



E-PUK (TO-200AB)

PRIMARY CHARACTERISTICS				
I _{T(AV)} 720 A				
V _{DRM} /V _{RRM}	400 V, 800 V, 1200 V, 1400 V, 1600 V			
V_{TM}	1.96 V			
I _{GT}	100 mA			
T _J	-40 °C to +125 °C			
Package	E-PUK (TO-200AB)			
Circuit configuration	Single SCR			

FEATURES

- · Center amplifying gate
- Metal case with ceramic insulator
- International standard case E-PUK (TO-200AB)



- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
1		720	А			
I _{T(AV)}	T _{hs}	55	°C			
1		1420	А			
I _T (RMS)	T _{hs}	25	°C			
1	50 Hz	9000	Λ			
ITSM	60 Hz	9420	A			
l ² t	50 Hz	405	- kA ² s			
1-1	60 Hz	370	- KA-S			
V _{DRM} /V _{RRM}		400 to 1600	V			
tq	Typical	100	μs			
T _J		-40 to 125	°C			

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$\begin{aligned} I_{DRM}/I_{RRM} & \text{MAXIMUM} \\ & \text{AT T}_{J} = \text{T}_{J} \\ & \text{MAXIMUM mA} \end{aligned}$				
	04	400	500					
08		800	900					
VS-ST330CC	12	1200	1300	50				
	14	1400	1500					
	16	1600	1700					



ABSOLUTE MAXIMUM RATINGS	3					
PARAMETER	SYMBOL		TEST CONDITIONS			
Maximum average on-state current	L	180° condu	ction, half sine v	vave	720 (350)	Α
at heatsink temperature	I _{T(AV)}	double side	(single side) co	oled	55 (75)	°C
Maximum RMS on-state current	I _{T(RMS)}	DC at 25 °C	heatsink tempe	erature double side cooled	1420	
		t = 10 ms	No voltage		9000	
Maximum peak, one-cycle		t = 8.3 ms	reapplied		9420	A kA ² s
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}		7570	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	7920	
Maximum I ² t for fusing	l ² t	t = 10 ms	No voltage reapplied	initial $T_J = T_J$ maximum	405	
		t = 8.3 ms			370	
		t = 10 ms			287	
		t = 8.3 ms	reapplied		262	
Maximum I ² √t for fusing	I²√t	t = 0.1 to 10	t = 0.1 to 10 ms, no voltage reapplied			kA²√s
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π	$x \mid_{T(AV)} < I < \pi x$	$I_{T(AV)}$), $T_J = T_J$ maximum	0.91	V
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)})$	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			V
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π	(16.7 % x π x $I_{T(AV)}$ < I < π x $I_{T(AV)}$), $T_J = T_J$ maximum			mΩ
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.57	1115.2
Maximum on-state voltage	V_{TM}	$I_{pk} = 1810 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$			1.96	V
Maximum holding current	I _H	T 05 °C	T 05 00 and a red 40 V with a lead			A
Typical latching current	ΙL	T _J = 25 °C, anode supply 12 V resistive load			1000	- mA

SWITCHING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum non-repetitive rate of rise of turned-on current	dI/dt	Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/μs			
Typical delay time	t _d	Gate current 1 A, $dl_g/dt = 1$ A/ μ s $V_d = 0.67 \% V_{DRM}$, $T_J = 25 °C$	1.0				
Typical turn-off time	t _q	I_{TM} = 550 A, T_J = T_J maximum, dl/dt = 40 A/μs, V_R = 50 V, dV/dt = 20 V/μs, gate 0 V 100 Ω , t_p = 500 μs	100	μs			

BLOCKING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated V_{DRM}	500	V/µs			
Maximum peak reverse and off-state leakage current	I _{RRM} , I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	50	mA			



TRIGGERING						
PARAMETER	SYMBOL	TEGT COURTEONS		VALUES		UNITS
PARAMETER	ARAMETER SYMBOL TEST CONDITIONS		51 CONDITIONS	TYP.	MAX.	UNITS
Maximum peak gate power	P _{GM}	$T_J = T_J$ maximum,	t _p ≤ 5 ms	10.0		w
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2.	.0	VV
Maximum peak positive gate current	I _{GM}	$T_J = T_J$ maximum,	t _p ≤ 5 ms	3.	.0	Α
Maximum peak positive gate voltage	+ V _{GM}	T T manyimay ma	t < E ma	20		V
Maximum peak negative gate voltage	- V _{GM}	$T_J = T_J$ maximum, $t_p \le 5$ ms			.0]
	I _{GT}	T _J = -40 °C	Maximum required gate trigger/ current/voltage are the lowest value which will trigger all units	200	-	mA
DC gate current required to trigger		T _J = 25 °C		100	200	
		T _J = 125 °C		50	-	
		T _J = -40 °C		2.5	-	
DC gate voltage required to trigger	V_{GT}	T _J = 25 °C	12 V anode to cathode applied	1.8	3.0	٧
		T _J = 125 °C		1.1	-	
DC gate current not to trigger	I _{GD}	T T	Maximum gate current/voltage not to trigger is the maximum	1	0	mA
DC gate voltage not to trigger	V _{GD}	ij=ijmaximum	$T_J = T_J$ maximum value which will not trigger any unit with rated V_{DRM} anode to cathode applied		0.25	

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum operating junction temperature range	T_J		-40 to 125	- °C		
Maximum storage temperature range	T _{Stg}		-40 to 150			
Maximum thermal resistance, junction to heatsink	D	DC operation single side cooled	0.09			
waximum thermal resistance, juriction to heatsink	R _{thJ-hs}	DC operation double side cooled	0.04	K/W		
Mariana di	R _{thC-hs}	DC operation single side cooled	0.02			
Maximum thermal resistance, case to heatsink		DC operation double side cooled	0.01			
Mounting force, ± 10 %			9800	N		
Widditing force, ± 10 %			(1000)	(kg)		
Approximate weight			83	g		
Case style		See dimensions - link at the end of datasheet	E-PUK (TO-2	200AB)		

△R _{thJ-hs} CONDUCTION							
CONDUCTION ANGLE	SINUSOIDAL	CONDUCTION	RECTANGULAR	R CONDUCTION	TEST CONDITIONS	UNITS	
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	TEST CONDITIONS	UNITS	
180°	0.012	0.011	0.008	0.007	$T_J = T_J$ maximum	K/W	
120°	0.014	0.012	0.014	0.013			
90°	0.017	0.015	0.019	0.017			
60°	0.025	0.022	0.026	0.023			
30°	0.043	0.036	0.043	0.037			

Note

• The table above shows the increment of thermal resistance Rthu-hs when devices operate at different conduction angles than DC

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130 Maximum Allowable Heatsink Temperature (°C) ST330C. C Series (Single Side Cooled) $R_{\text{thJ-hs}} (DC) = 0.09 \text{ K/W}$ 120 110 Conduction Angle 100 309 90 90° 180° 80

Fig. 1 - Current Ratings Characteristics

Average On-state Current (A)

100 150 200 250 300 350 400

50

0

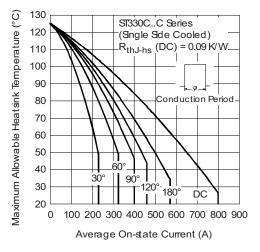
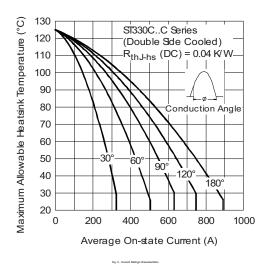
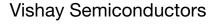


Fig. 2 - Current Ratings Characteristics





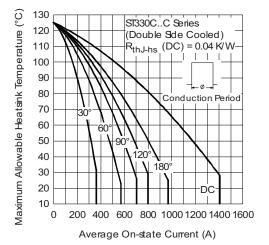


Fig. 4 - Current Ratings Characteristics

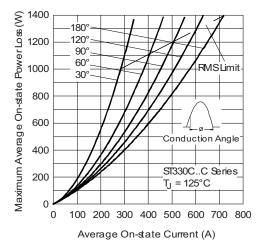


Fig. 5 - On-State Power Loss Characteristics

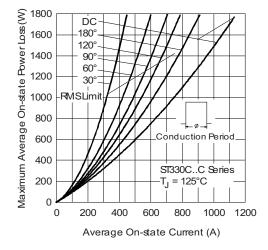


Fig. 6 - On-State Power Loss Characteristics

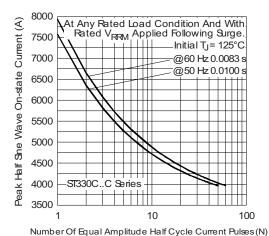


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

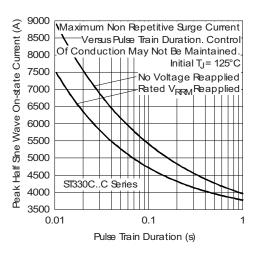


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

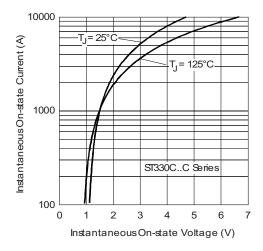


Fig. 9 - On-State Voltage Drop Characteristics

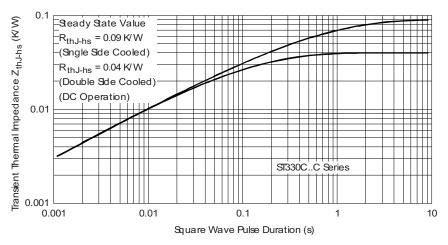


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics

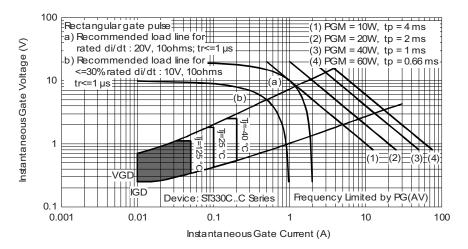
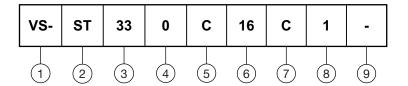


Fig. 11 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Thyristor

Essential part number

4 - 0 = converter grade

5 - C = ceramic PUK

6 - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)

7 - C = PUK case E-PUK (TO-200AB)

8 - 0 = eyelet terminals (gate and auxiliary cathode unsoldered leads)

1 = fast-on terminals (gate and auxiliary cathode unsoldered leads)

2 = eyelet terminals (gate and auxiliary cathode soldered leads)

3 = fast-on terminals (gate and auxiliary cathode soldered leads)

9 - Critical dV/dt: • None = 500 V/µs (standard selection)

• L = 1000 V/µs (special selection)

LINKS TO RELAT	ED DOCUMENTS
Dimensions	http://www.vishay.com/doc?95075

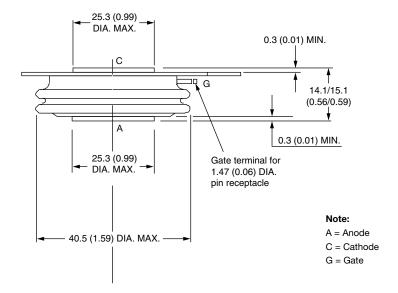


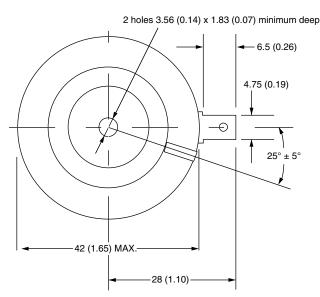
E-PUK (TO-200AB)

DIMENSIONS in millimeters (inches)

Anode to gate

Creepage distance: 11.18 (0.44) minimum Strike distance: 7.62 (0.30) minimum





Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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T300N14TOF T3710N06TOF VT T390N16TOF T460N24TOF T501N70TOH T560N16TOF T640N14TOF TD250N14KOF
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T360N22TOF TZ810N22KOF